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☐ Emerging Tech		Sony Evaluates and Eradicates Plasma Damage			
☐ Inspection, Measurement & Test ☐ Lithography	Suppressing Abnormal D	ischarges in Plasma Processes			
☐ Materials Science	Laura Peters, Senior Editor Semiconductor International , 11/1/2005				
☐ Optoelectronics ☐ Semiconductor					
Packaging	All plasma processes share a common problem that affects yield. Abnormal electric discharges can create particulate matter and cause physical and/or electrical damage				
☐ Vacuum	to the wafer. Such discharges can also cause the resulting plasma to be unstable.				
☐ Wafer Processing ☐ Yield Management	•				
□ reiù warayement i	A group of researchers determined that they could effectively detect and suppress anomalous discharges in plasma equipment using the signals from two probes that can				
	predict the occurrence of abnormal discharges. The discharges are then suppressed by				
×					
	ne Ariake National College of Technology in Fukuoka, Ja				
	colleagues with the Tokyo Cathode Lab (Kumamoto, Japan), NEC Elect				
	Industrial Research Institute and the Kyushu Institute of Technology.				
	The researchers used two sen-	sors: an acoustic emission (AE) sensor and a view-port (
	The VP probe was specifically	designed for this application and is able to detect change			
Current Issue	potential just prior to anomalou	is electrical discharge. The AE sensor detects the acoust			
×	emitted from the point where the discharge occurred. The detection of a supersonic wa independent of plasma generation method (DC or RF).				
	, ,	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,			
Registration		ent electrode film made of indium tin oxide, which is posi-			
Sign up today for special		glass and the outer, thick glass of the RIE system's view harge buildup at the inner glass surface of the viewing po			
features, including free	detectors are able to monitor the	ne occurrence of abnormal discharge, and can also be us			
e-letters, access to archives, and much	the location of the discharge by	analyzing the acoustic signals detected by multiple AE nside the process tool. The AE sensor was attached to t			
more. Register		ensors located around the periphery of the chamber. The			
Tools and Services	used an in situ particle monitoring system capable of detecting titanium particles >70 nr				
	The percilal slate DIC and the	and 40 50 th) in avaitable with a series of a series of the series of th			
☐ Archives	The parallel-plate RIE system used 13.56 MHz excitation voltage, and anomalous disci- induced using moisture on a titanium-coated wafer mounted on the RF electrode by an				
☐ Business/Financial Info		side cooling. RF power of 1000 W was supplied. Gases c			
☐ Buyers Guide –	were used. The discharge pressure was 30 Pa. The researchers monitored the AE and				
SemiSource Industry Connection	sensor signals using a multicha	annel digital data recorder.			
	Monitoring showed the VP prof	be was very sensitive to change in electrical potential, sh			
In-Stat Research	members of profession of prof	rory contains to offerigo in bloodings potential, all			

Store Market Research Newsletters Reference Special Reports Talk Back Web Connection	increased a a plasma state. The A	t the moment that the and ate where the plasma der AE sensor detected the ch	s indicates that the flux of omalous discharge occurrensity and/or electron temperange in potential just millist e AE wave along the chance Signal waveform of the view-port probe	ed. The anomalous disclerature was higher than seconds after the VP pro	
Inside SI			shows that the		
☐ About us			indicating signal		
☐ Advertising			appears prior to the anomalous		
☐ Awards			discharges.		
☐ Contact Us					
☐ Editorial Calendar	Moisture in	the chamber caused abou	ormal discharges to occur	~3 sec apart for 10 min	
☐ Submit an Article	Moisture in the chamber caused abnormal discharges to occur ~3 sec apart for 10 min. wafer was replaced with another wafer with moisture, the same phenomena occurred.				
☐ Submit a Press Release	the particle monitor were coincident with the AE sensor and VP probe signals.				
☐ Free Subscriptions	The group o	letermined that, by lowering	ng the voltage applied to the	ne ESC wafer stage, fev	
Reed Electronics Group Websites □ ECN □ EDN	voltage using the ESC vol	g the foreseeing signal as	developed an electric feeds a trigger. The system corstem that records the disciplints.	nsists of an A/D convert	
☐ Electronic Business ☐ Electronic News ☐ In-Stat	The feedback system responds to the foreseeing signal of the VP probe and applies vo ESC. When the ESC voltage control is employed, the anomalous discharge is complete suppressed.				
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